

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	"257"/\$.ccls. and intra adj substrate adj pad	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 17:00
L2	3	intra adj substrate adj pad	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:32
L3	386	pad near3 (within or inside) near3 substrate and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 12:48
L4	158	pad near3 (within or inside) near3 substrate and semiconductor and wire adj bond\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 12:48
L5	2	("20010048591" "6407459").PN. OR ("6864565").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/20 13:28
L6	2	("6025651").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/04/20 13:28
L7	2	("20050218509").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/04/20 13:34
L8	2	("6753544").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/04/20 13:34
L9	31	("4303930" "4516146" "5090932" "5414272" "5473218" "5554859" "5557596" "5559342" "5696385" "5702281" "5726524" "5760417" "5814832" "5982091" "6008576" "6011356" "6023124" "6034479" "6064149" "6096570" "6107732" "6137212" "6166487" "6229758" "6249080" "6329745" "6400070" "6445124" "6469425").PN. OR ("6753544").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/20 14:27
L10	2	("6774718").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/04/20 14:27

EAST Search History

L11	5	("5656972" "5732334" "6417730" "6639466").PN. OR ("6774718").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/20 14:30
L12	8	"6025651"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 14:34
L13	13	"5446309"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 14:36
L14	20	US-5446309-\$.DID. OR US-6274937-\$.DID. OR US-6529093-\$.DID. OR US-6531668-\$.DID. OR US-6573822-\$.DID. OR US-6822535-\$.DID. OR US-6850133-\$.DID. OR US-6880235-\$.DID. OR US-6933808-\$.DID. OR US-6972650-\$.DID.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 14:39
L15	2	("6642617").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/04/20 14:39
L16	4	("5918112" "6351194" "6396154" "6534855").PN. OR ("6642617").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/04/20 14:47
L17	2093	active near5 substrate and passive near5 substrate and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 14:52
L18	159	plurality near5 active near5 substrate and passive near5 substrate and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:01
L19	8	US-6203587-\$.DID. OR US-6183703-\$.DID. OR US-4977041-\$.DID. OR US-6630372-\$.DID.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 14:59
L20	987	plurality near2 active near2 substrate and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:05
L21	5	plurality adj active adj substrate and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:41
L22	1	intra adj substrate adj pad and "20040232982".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:32

EAST Search History

L23	1639840	plurality adj substrate near5 (transistor or diode) semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:49
L24	43	plurality adj substrate near5 (transistor or diode) and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:51
L25	2	"20040232982"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 15:57
L26	50	substrate and embedded and interconnection and intel.as. and wire	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 16:05
L27	877	substrate near10 embedded near10 (interconnection or trace or pad)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 16:11
L28	460	substrate near5 embedded near5 (interconnection or trace or pad)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 16:15
L29	7	power adj amplifier and mems adj switch and substrate and bonding adj pads and wire	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 16:57
L30	41040	substrate same (passive or active) same (transistor or diode)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 17:00
L31	341	"257"/\$.ccls. and active adj substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/04/20 17:03